

## Phase Control Thyristors (Hockey PUK Version), 990 A



B-PUK (TO-200AC)



### FEATURES

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case B-PUK (TO-200AC)
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

### TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

PRIMARY CHARACTERISTICS	
$I_{T(AV)}$	990 A
$V_{DRM}/V_{RRM}$	800 V, 1200 V, 1400 V, 1600 V, 1800 V, 2000 V
$V_{TM}$	1.62 V
$I_{GT}$	100 mA
$T_J$	-40 °C to +125 °C
Package	B-PUK (TO-200AC)
Circuit configuration	Single SCR

MAJOR RATINGS AND CHARACTERISTICS			
PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{T(AV)}$		990	A
	$T_{hs}$	55	°C
$I_{T(RMS)}$		2000	A
	$T_{hs}$	25	°C
$I_{TSM}$	50 Hz	17 800	A
	60 Hz	18 700	
$I^2t$	50 Hz	1591	$kA^2s$
	60 Hz	1452	
$V_{DRM}/V_{RRM}$		800 to 2000	V
$t_q$	Typical	150	μs
$T_J$		-40 to 125	°C

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	$V_{DRM}/V_{RRM}$ , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	$V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$I_{DRM}/I_{RRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM mA
VS-ST730CL	08	800	900	80
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	
	18	1800	1900	
	20	2000	2100	

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS	
Maximum average on-state current at heatsink temperature	$I_{T(AV)}$	180° conduction, half sine wave double side (single side) cooled			990 (375)	A	
					55 (85)	°C	
Maximum RMS on-state current	$I_{T(RMS)}$	DC at 25 °C heatsink temperature double side cooled			2000	A	
Maximum peak, one-cycle non-repetitive surge current	$I_{TSM}$	$t = 10 \text{ ms}$	No voltage reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	17 800		
		$t = 8.3 \text{ ms}$	18 700				
		$t = 10 \text{ ms}$	100 % $V_{RRM}$ reapplied		15 000		
		$t = 8.3 \text{ ms}$	15 700				
Maximum $I^2t$ for fusing	$I^2t$	$t = 10 \text{ ms}$	No voltage reapplied	1591 1452 1125 1027	1591	mA <sup>2</sup> s	
		$t = 8.3 \text{ ms}$	1452				
		$t = 10 \text{ ms}$	100 % $V_{RRM}$ reapplied		1125		
		$t = 8.3 \text{ ms}$	1027				
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1 \text{ to } 10 \text{ ms}$ , no voltage reapplied			15 910	kA <sup>2</sup> √s	
Low level value of threshold voltage	$V_{T(TO)1}$	$(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_J$ maximum			0.98	V	
High level value of threshold voltage	$V_{T(TO)2}$	$(I > \pi \times I_{T(AV)})$ , $T_J = T_J$ maximum			1.12		
Low level value of on-state slope resistance	$r_{t1}$	$(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_J$ maximum			0.32	mΩ	
High level value of on-state slope resistance	$r_{t2}$	$(I > \pi \times I_{T(AV)})$ , $T_J = T_J$ maximum			0.27		
Maximum on-state voltage	$V_{TM}$	$I_{pk} = 2000 \text{ A}$ , $T_J = T_J$ maximum, $t_p = 10 \text{ ms}$ sine pulse			1.62	V	
Maximum holding current	$I_H$	$T_J = 25 \text{ °C}$ , anode supply 12 V resistive load			600	mA	
Typical latching current	$I_L$				1000		

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	$dI/dt$	Gate drive 20 V, 20 Ω, $t_r \leq 1 \mu\text{s}$ $T_J = T_J$ maximum, anode voltage $\leq 80 \% V_{DRM}$			1000	A/μs
Typical delay time	$t_d$	Gate current 1 A, $dI_g/dt = 1 \text{ A/}\mu\text{s}$ $V_d = 0.67 \% V_{DRM}$ , $T_J = 25 \text{ °C}$			1.0	μs
Typical turn-off time	$t_q$	$I_{TM} = 750 \text{ A}$ , $T_J = T_J$ maximum, $dI/dt = 60 \text{ A/}\mu\text{s}$ , $V_R = 50 \text{ V}$ , $dV/dt = 20 \text{ V/}\mu\text{s}$ , gate 0 V 100 Ω, $t_p = 500 \mu\text{s}$			150	

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum critical rate of rise of off-state voltage	$dV/dt$	$T_J = T_J$ maximum linear to 80 % rated $V_{DRM}$			500	V/μs
Maximum peak reverse and off-state leakage current	$I_{RRM}$ , $I_{DRM}$	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied			80	mA

TRIGGERING						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES		UNITS
		Typ.	Max.			
Maximum peak gate power	$P_{GM}$	$T_J = T_J$ maximum, $t_p \leq 5$ ms		10.0		W
Maximum average gate power	$P_{G(AV)}$	$T_J = T_J$ maximum, $f = 50$ Hz, $d\% = 50$		2.0		
Maximum peak positive gate current	$I_{GM}$	$T_J = T_J$ maximum, $t_p \leq 5$ ms		3.0		A
Maximum peak positive gate voltage	$+V_{GM}$	$T_J = T_J$ maximum, $t_p \leq 5$ ms		20		V
Maximum peak negative gate voltage	$-V_{GM}$			5.0		
DC gate current required to trigger	$I_{GT}$	$T_J = -40$ °C	Maximum required gate trigger/current/voltage are the lowest value which will trigger all units 12 V anode to cathode applied	200	-	mA
		$T_J = 25$ °C		100	200	
		$T_J = 125$ °C		50	-	
DC gate voltage required to trigger	$V_{GT}$	$T_J = -40$ °C	12 V anode to cathode applied	2.5	-	V
		$T_J = 25$ °C		1.8	3.0	
		$T_J = 125$ °C		1.1	-	
DC gate current not to trigger	$I_{GD}$	$T_J = T_J$ maximum	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated $V_{DRM}$ anode to cathode applied	10		mA
DC gate voltage not to trigger	$V_{GD}$			0.25		V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum operating junction temperature range	$T_J$			-40 to 125	°C
Maximum storage temperature range	$T_{Stg}$			-40 to 150	
Maximum thermal resistance, junction to heatsink	$R_{thJ-hs}$	DC operation single side cooled		0.073	K/W
		DC operation double side cooled		0.031	
Maximum thermal resistance, case to heatsink	$R_{thC-hs}$	DC operation single side cooled		0.011	
		DC operation double side cooled		0.006	
Mounting force, $\pm 10$ %				14 700 (1500)	N (kg)
Approximate weight				255	g
Case style		See dimensions - link at the end of datasheet		B-PUK (TO-200AC)	

$\Delta R_{thJ-hs}$ CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS
	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE		
180°	0.009	0.009	0.006	0.006	$T_J = T_J$ maximum	K/W
120°	0.011	0.011	0.010	0.011		
90°	0.014	0.014	0.015	0.015		
60°	0.020	0.020	0.021	0.021		
30°	0.036	0.036	0.036	0.036		

**Note**

- The table above shows the increment of thermal resistance  $R_{thJ-hs}$  when devices operate at different conduction angles than DC

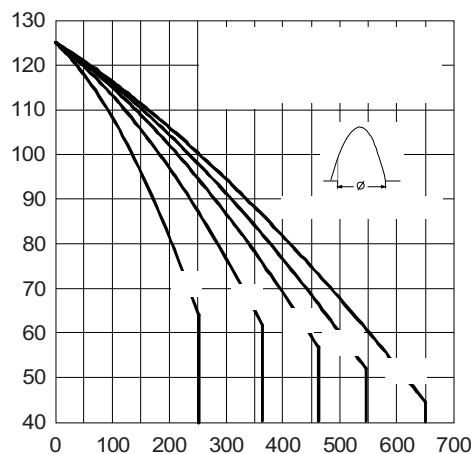


Fig. 1 - Current Ratings Characteristics

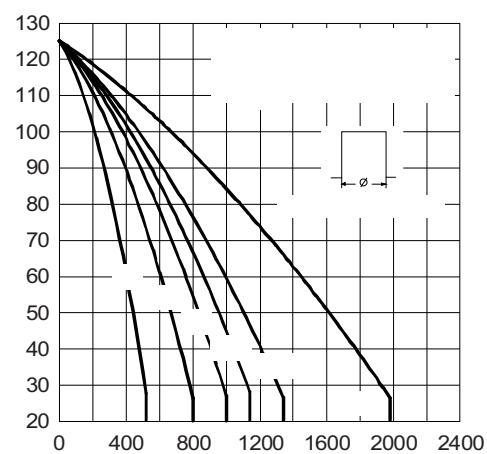


Fig. 4 - Current Ratings Characteristics

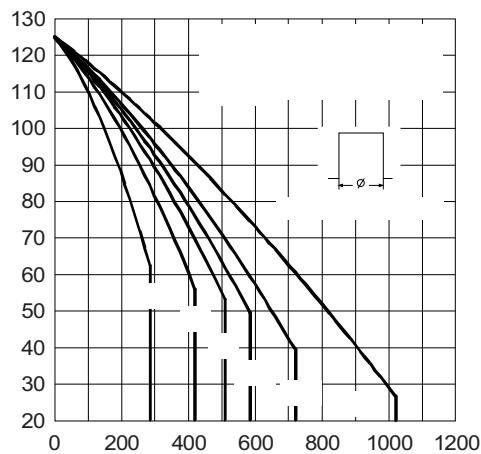


Fig. 2 - Current Ratings Characteristics

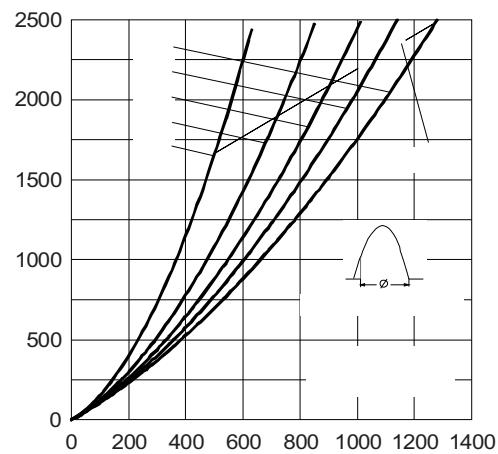


Fig. 5 - On-State Power Loss Characteristics

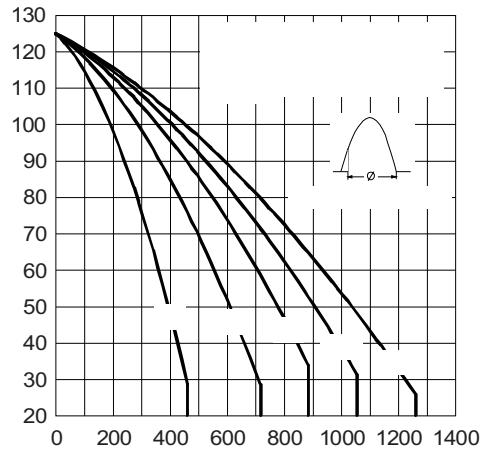


Fig. 3 - Current Ratings Characteristics

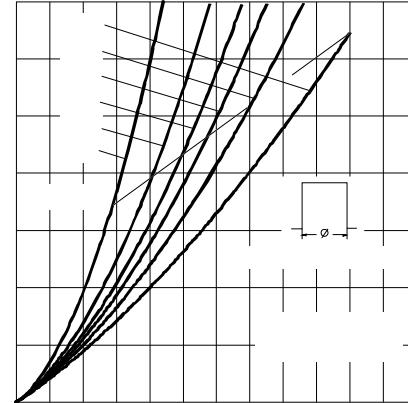
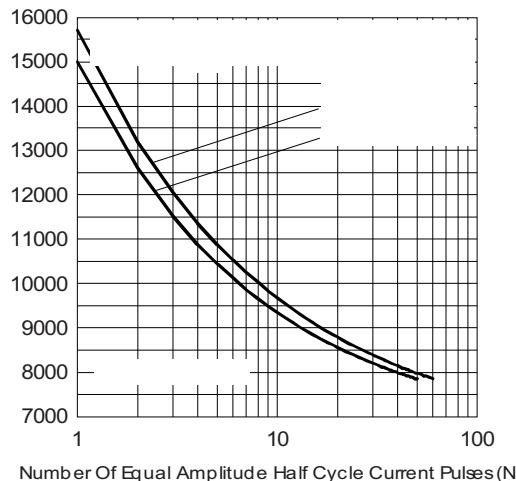


Fig. 6 - On-State Power Loss Characteristics



Number Of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 7 - Maximum Non-Repetitive Surge Current  
Single and Double Side Cooled

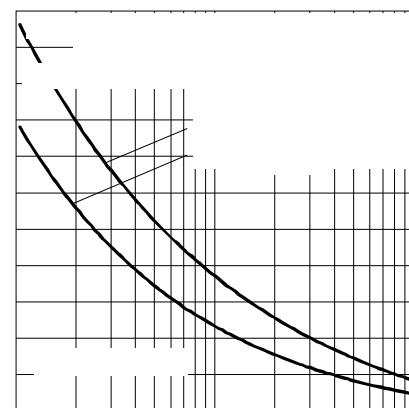


Fig. 8 - Maximum Non-Repetitive Surge Current  
Single and Double Side Cooled

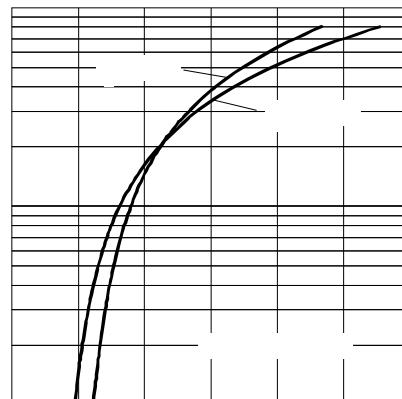


Fig. 9 - On-State Voltage Drop Characteristics

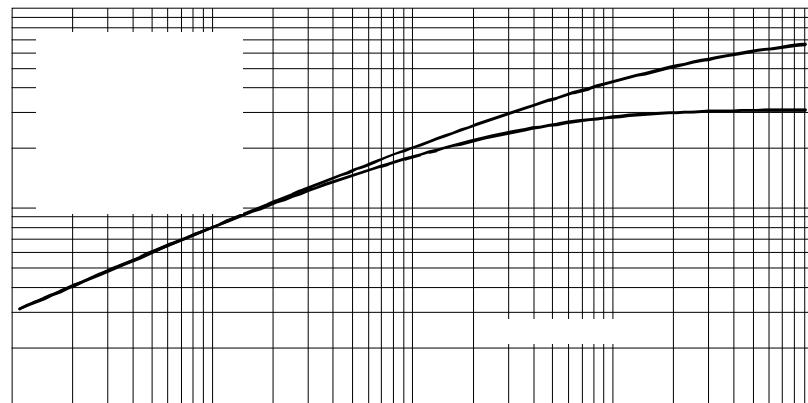


Fig. 10 - Thermal Impedance  $Z_{thJ-hs}$  Characteristics

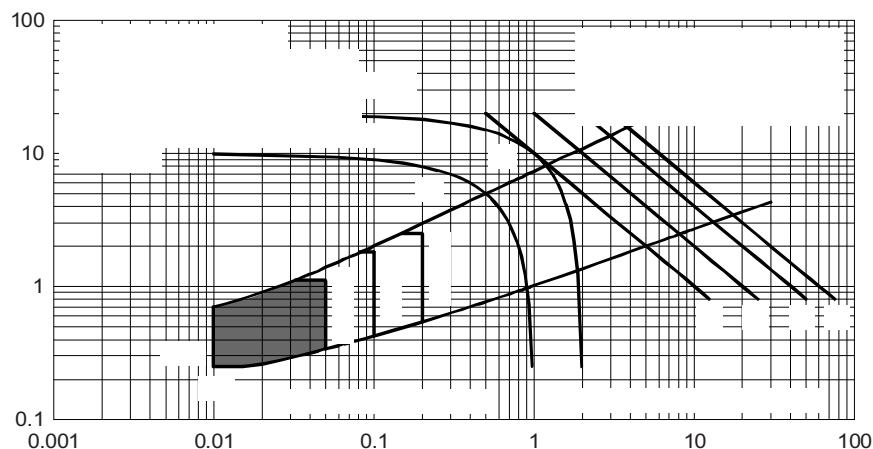


Fig. 11 - Gate Characteristics

**ORDERING INFORMATION TABLE**

Device code	VS-	ST	73	0	C	20	L	1	-
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)
<b>1</b>	- Vishay Semiconductors product								
<b>2</b>	- Thyristor								
<b>3</b>	- Essential part number								
<b>4</b>	- 0 = converter grade								
<b>5</b>	- C = ceramic PUK								
<b>6</b>	- Voltage code x 100 = $V_{RRM}$ (see Voltage Ratings table)								
<b>7</b>	- L = PUK case B-PUK (TO-200AC)								
<b>8</b>	- 0 = eyelet terminals (gate and auxiliary cathode unsoldered leads)								
	1 = fast-on terminals (gate and auxiliary cathode unsoldered leads)								
	2 = eyelet terminals (gate and auxiliary cathode soldered leads)								
	3 = fast-on terminals (gate and auxiliary cathode soldered leads)								
<b>9</b>	- Critical dV/dt: • None = 500 V/μs (standard selection)								
	• L = 1000 V/μs (special selection)								

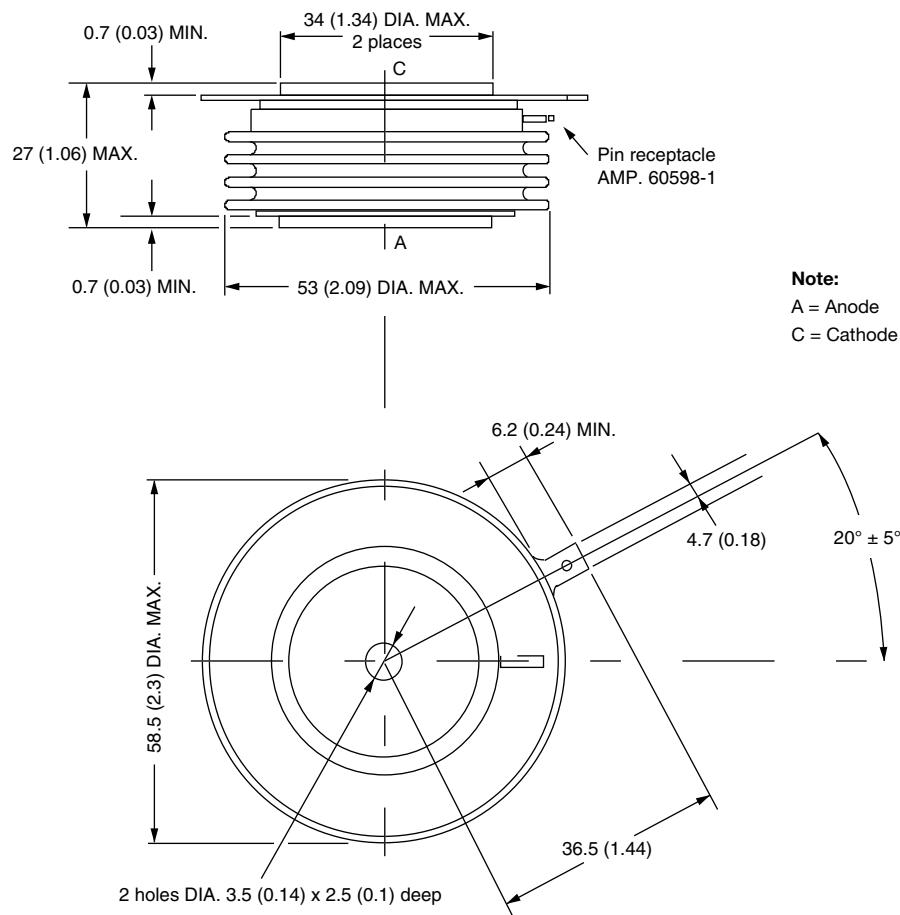
**LINKS TO RELATED DOCUMENTS**

Dimensions	<a href="http://www.vishay.com/doc?95076">www.vishay.com/doc?95076</a>
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### B-PUK (TO-200AC)

**DIMENSIONS** in millimeters (inches)

Creepage distance: 36.33 (1.430) minimum  
 Strike distance: 17.43 (0.686) minimum



Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)

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